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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I²C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, Cap Sense, DMA, I²S, POR, PWM, WDT
Number of I/O	37
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 14x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l151cct6j

The memory protection unit (MPU) improves system reliability by defining the memory attributes (such as read/write access permissions) for different memory regions. It provides up to eight different regions and an optional predefined background region.

Owing to its embedded ARM core, the STM32L151xC and STM32L152xC devices are compatible with all ARM tools and software.

Nested vectored interrupt controller (NVIC)

The ultra-low-power STM32L151xC and STM32L152xC devices embed a nested vectored interrupt controller able to handle up to 53 maskable interrupt channels (not including the 16 interrupt lines of ARM® Cortex®-M3) and 16 priority levels.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support for tail-chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimal interrupt latency.

3.3 Reset and supply management

3.3.1 Power supply schemes

- V_{DD} = 1.65 to 3.6 V: external power supply for I/Os and the internal regulator. Provided externally through V_{DD} pins.
- V_{SSA}, V_{DDA} = 1.65 to 3.6 V: external analog power supplies for ADC, reset blocks, RCs and PLL (minimum voltage to be applied to V_{DDA} is 1.8 V when the ADC is used). V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS}, respectively.

3.3.2 Power supply supervisor

The device has an integrated ZEROPOWER power-on reset (POR)/power-down reset (PDR) that can be coupled with a brownout reset (BOR) circuitry.

The device exists in two versions:

- The version with BOR activated at power-on operates between 1.8 V and 3.6 V.
- The other version without BOR operates between 1.65 V and 3.6 V.

After the V_{DD} threshold is reached (1.65 V or 1.8 V depending on the BOR which is active or not at power-on), the option byte loading process starts, either to confirm or modify default thresholds, or to disable the BOR permanently: in this case, the V_{DD} min value becomes 1.65 V (whatever the version, BOR active or not, at power-on).

When BOR is active at power-on, it ensures proper operation starting from 1.8 V whatever the power ramp-up phase before it reaches 1.8 V. When BOR is not active at power-up, the

3.17.2 Universal synchronous/asynchronous receiver transmitter (USART)

The three USART interfaces are able to communicate at speeds of up to 4 Mbit/s. They support IrDA SIR ENDEC and have LIN Master/Slave capability. The three USARTs provide hardware management of the CTS and RTS signals and are ISO 7816 compliant.

All USART interfaces can be served by the DMA controller.

3.17.3 Serial peripheral interface (SPI)

Up to three SPIs are able to communicate at up to 16 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

The SPIs can be served by the DMA controller.

3.17.4 Inter-integrated sound (I^2S)

Two standard I2S interfaces (multiplexed with SPI2 and SPI3) are available. They can operate in master or slave mode, and can be configured to operate with a 16-/32-bit resolution as input or output channels. Audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the I2S interfaces is/are configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

The I2Ss can be served by the DMA controller.

3.17.5 Universal serial bus (USB)

The STM32L151xC and STM32L152xC devices embed a USB device peripheral compatible with the USB full-speed 12 Mbit/s. The USB interface implements a full-speed (12 Mbit/s) function interface. It has software-configurable endpoint setting and supports suspend/resume. The dedicated 48 MHz clock is generated from the internal main PLL (the clock source must use a HSE crystal oscillator).

3.18 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

Table 9. STM32L151xC and STM32L152xC pin definitions (continued)

Pins					Pin name	Pin type[1]	I / O Structure	Main function[2] (after reset)	Pin functions	
UFBGA100	LQFP100	LQFP64	WLCSP63	LQFP48 or UFQFPN48					Alternate functions	Additional functions
M6	36	27	H3	19	PB1	I/O	FT	PB1	TIM3_CH4/LCD_SEG6	ADC_IN9/ COMP1_INP/ VREF_OUT
L6	37	28	G3	20	PB2	I/O	FT	PB2 /BOOT1	BOOT1	VLCDRAIL1/ ADCIN0b
M7	38	-	-	-	PE7	I/O	TC	PE7	-	ADC_IN22/ COMP1_INP
L7	39	-	-	-	PE8	I/O	TC	PE8	-	ADC_IN23/ COMP1_INP
M8	40	-	-	-	PE9	-	TC	PE9	TIM2_CH1_ETR/ TIM5_ETR	ADC_IN24/ COMP1_INP
L8	41	-	-	-	PE10	I/O	TC	PE10	TIM2_CH2	ADC_IN25/ COMP1_INP
M9	42	-	-	-	PE11	I/O	FT	PE11	TIM2_CH3	VLCDRAIL2
L9	43	-	-	-	PE12	I/O	FT	PE12	TIM2_CH4/SPI1_NSS	VLCDRAIL3
M10	44	-	-	-	PE13	I/O	FT	PE13	SPI1_SCK	-
M11	45	-	-	-	PE14	I/O	FT	PE14	SPI1_MISO	-
M12	46	-	-	-	PE15	I/O	FT	PE15	SPI1_MOSI	-
L10	47	29	J2	21	PB10	I/O	FT	PB10	TIM2_CH3/I2C2_SCL/ USART3_TX/ LCD_SEG10	-
L11	48	30	H2	22	PB11	I/O	FT	PB11	TIM2_CH4/I2C2_SDA/ USART3_RX/ LCD_SEG11	-
-	-	-	H5	-	V_{SS}	S	-	V_{SS}	-	-
F12	49	31	J1	23	V_{SS_1}	S	-	V_{SS_1}	-	-
G12	50	32	H1	24	V_{DD_1}	S	-	V_{DD_1}	-	-

Table 9. STM32L151xC and STM32L152xC pin definitions (continued)

Pins					Pin name	Pin type(1)	I / O Structure	Main function(2) (after reset)	Pin functions	
UFBGA100	LQFP100	LQFP64	WLCSP63	LQFP48 or UFQFPN48					Alternate functions	Additional functions
C10	79	52	A3	-	PC11	I/O	FT	PC11	SPI3_MISO/ USART3_RX/ LCD_SEG29/ LCD_SEG41/ LCD_COM5	-
B10	80	53	B4	-	PC12	I/O	FT	PC12	SPI3_MOSI/I2S3_SD/ USART3_CK/ LCD_SEG30/ LCD_SEG42/ LCD_COM6	-
C9	81	-	-	-	PD0	I/O	FT	PD0	TIM9_CH1/SPI2_NSS/ I2S2_WS	-
B9	82	-	-	-	PD1	I/O	FT	PD1	SPI2_SCK/I2S2_CK	-
C8	83	54	A4	-	PD2	I/O	FT	PD2	TIM3_ETR/LCD_SEG31 /LCD_SEG43/ LCD_COM7	-
B8	84	-	-	-	PD3	I/O	FT	PD3	SPI2_MISO/ USART2_CTS	-
B7	85	-	-	-	PD4	I/O	FT	PD4	SPI2_MOSI/I2S2_SD/ USART2_RTS	-
A6	86	-		-	PD5	I/O	FT	PD5	USART2_TX	-
B6	87	-	-	-	PD6	I/O	FT	PD6	USART2_RX	-
A5	88	-	-	-	PD7	I/O	FT	PD7	TIM9_CH2/USART2_CK	-
A8	89	55	C4	39	PB3	I/O	FT	JTDO	TIM2_CH2/SPI1_SCK/ SPI3_SCK/I2S3_CK/ LCD_SEG7/JTDO	COMP2_INM
A7	90	56	D4	40	PB4	I/O	FT	NJTRST	TIM3_CH1/SPI1_MISO/ SPI3_MISO/LCD_SEG8 /NJTRST	COMP2_INP
C5	91	57	A5	41	PB5	I/O	FT	PB5	TIM3_CH2/I2C1_SMBA/ SPI1_MOSI/SPI3_MOSI /I2S3_SD/LCD_SEG9	COMP2_INP

Table 10. Alternate function input/output (continued)

Port name	Digital alternate function number								. .		. .		
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFIO6	AFIO7		AFIO11		AFIO14	AFIO15
	Alternate function												
	SYSTEM	TIM2	TIM3/4/5	TIM9/ 10/11	I2C1/2	SPI1/2	SPI3	USART1/2/3		LCD		CPRI	SYSTEM
PE8	-	-	-	-	-	-	-	-		-		TIMx_IC1	EVENT OUT
PE9	-	TIM2_CH1_ETR	TIM5_ETR	-	-	-	-	-		-		TIMx_IC2	EVENT OUT
PE10	-	TIM2_CH2	-	-	-	-	-	-		-		TIMx_IC3	EVENT OUT
PE11	-	TIM2_CH3	-	-	-	-	-	-		-		TIMx_IC4	EVENT OUT
PE12	-	TIM2_CH4	-	-	-	SPI1_NSS	-	-		-		TIMx_IC1	EVENT OUT
PE13	-	-	-	-	-	SPI1_SCK	-	-		-		TIMx_IC2	EVENT OUT
PE14	-	-	-	-	-	SPI1_MISO	-	-		-		TIMx_IC3	EVENT OUT
PE15	-	-	-	-	-	SPI1_MOSI	-	-		-		TIMx_IC4	EVENT OUT
PH0OSC _IN	-	-	-	-	-	-	-	-		-		-	-
PH1OSC_ OUT	-	-	-	-	-	-	-	-		-		-	-
PH2	-	-	-	-	-	-	-	-		-		-	-

Table 23. Typical and maximum current consumptions in Stop mode (continued)

Symbol	Parameter	Conditions		Typ	Max(1)	Unit
I_{DD} (Stop)	Supply current in Stop mode (RTC disabled)	Regulator in LP mode, HSI and HSE OFF, independent watchdog and LSI enabled	T_A = -40°C to 25°C	1.8	2.2	µA
		Regulator in LP mode, LSI, HSI and HSE OFF (no independent watchdog)	T_A = -40°C to 25°C	0.435	1	
			T_A = 55°C	0.99	3	
			T_A= 85°C	2.4	9	
			T_A = 105°C	5.5	22(5)	
I_{DD} (WU from Stop)	Supply current during wakeup from Stop mode	MSI = 4.2 MHz	T_A = -40°C to 25°C	2	-	mA
		MSI = 1.05 MHz		1.45	-	
		MSI = 65 kHz(6)		1.45	-	

1. Guaranteed by characterization results, unless otherwise specified.
2. LCD enabled with external VLCD, static duty, division ratio = 256, all pixels active, no LCD connected.
3. LCD enabled with external VLCD, 1/8 duty, 1/3 bias, division ratio = 64, all pixels active, no LCD connected.
4. Based on characterization done with a 32.768 kHz crystal (MC306-G-06Q-32.768, manufacturer JFVNY) with two 6.8 pF loading capacitors.
5. Guaranteed by test in production.
6. When MSI = 64 kHz, the RMS current is measured over the first 15 µs following the wakeup event. For the remaining part of the wakeup period, the current corresponds the Run mode current.

Table 59. DAC characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
dOffset/dT(1)	Offset error temperature coefficient (code 0x800)	V_{DDA} = 3.3V V_{REF+} = 3.0V T_A = 0 to 50 °C DAC output buffer OFF	-20	-10	0	µV/°C
		V_{DDA} = 3.3V V_{REF+} = 3.0V T_A = 0 to 50 °C DAC output buffer ON	0	20	50	
Gain(1)	Gain error(7)	C_L 50 pF, R_L 5 k DAC output buffer ON	-	+0.1 / -0.2%	+0.2 / -0.5%	%
		No R_L, C_L 50 pF DAC output buffer OFF	-	+0 / -0.2%	+0 / -0.4%	
dGain/dT(1)	Gain error temperature coefficient	V_{DDA} = 3.3V V_{REF+} = 3.0V T_A = 0 to 50 °C DAC output buffer OFF	-10	-2	0	µV/°C
		V_{DDA} = 3.3V V_{REF+} = 3.0V T_A = 0 to 50 °C DAC output buffer ON	-40	-8	0	
TUE(1)	Total unadjusted error	C_L 50 pF, R_L 5 k DAC output buffer ON	-	12	30	LSB
		No R_L, C_L 50 pF DAC output buffer OFF	-	8	12	
$t_{SETTLING}$	Settling time (full scale: for a 12-bit code transition between the lowest and the highest input codes till DAC_OUT reaches final value ±1LSB	C_L 50 pF, R_L 5 k	-	7	12	µs
Update rate	Max frequency for a correct DAC_OUT change (95% of final value) with 1 LSB variation in the input code	C_L 50 pF, R_L 5 k	-	-	1	Msps
t_{WAKEUP}	Wakeup time from off state (setting the ENx bit in the DAC Control register)(8)	C_L 50 pF, R_L 5 k	-	9	15	µs
PSRR+	V_{DDA} supply rejection ratio (static DC measurement)	C_L 50 pF, R_L 5 k	-	-60	-35	dB

1. Data based on characterization results.
2. Connected between DAC_OUT and V_{SSA}.
3. Difference between two consecutive codes - 1 LSB.

Table 60. Operational amplifier characteristics (continued)

Symbol	Parameter		Condition(1)	Min(2)	Typ	Max(2)	Unit
PSRR	Power supply rejection ratio	Normal mode	DC	-	-85	-	dB
		Low-power mode		-	-90	-	
GBW	Bandwidth	Normal mode	V_{DD}>2.4 V	400	1000	3000	kHZ
		Low-power mode		150	300	800	
		Normal mode	V_{DD}<2.4 V	200	500	2200	
		Low-power mode		70	150	800	
SR	Slew rate	Normal mode	V_{DD}>2.4 V (between 0.1 V and V_{DD}-0.1 V)	-	700	-	V/ms
		Low-power mode	V_{DD}>2.4 V	-	100	-	
		Normal mode	V_{DD}<2.4 V	-	300	-	
		Low-power mode		-	50	-	
AO	Open loop gain	Normal mode		55	100	-	dB
		Low-power mode		65	110	-	
R_L	Resistive load	Normal mode	V_{DD}<2.4 V	4	-	-	k
		Low-power mode		20	-	-	
C_L	Capacitive load		-	-	-	50	pF
VOH_{SAT}	High saturation voltage	Normal mode	I_{LOAD} = max or R_L = min	V_{DD}-100	-	-	mV
		Low-power mode		V_{DD}-50	-	-	
VOL_{SAT}	Low saturation voltage	Normal mode		-	-	100	
		Low-power mode		-	-	50	
m	Phase margin		-	-	60	-	°
GM	Gain margin		-	-	-12	-	dB
$t_{OFFTRIM}$	Offset trim time: during calibration, minimum time needed between two steps to have 1 mV accuracy		-	-	1	-	ms
t_{WAKEUP}	Wakeup time	Normal mode	C_L 50 pf, R_L 4 k	-	10	-	µs
		Low-power mode	C_L 50 pf, R_L 20 k	-	30	-	

1. Operating conditions are limited to junction temperature (0 °C to 105 °C) when V_{DD} is below 2 V. Otherwise to the full ambient temperature range (-40 °C to 85 °C, -40 °C to 105 °C).
2. Guaranteed by characterization results.

7.7 Thermal characteristics

The maximum chip-junction temperature, T_J max, in degrees Celsius, may be calculated using the following equation:

T_J max = T_A max + (P_D max × $_{JA}$)

Where:

- T_A max is the maximum ambient temperature in °C,
- $_{JA}$ is the package junction-to-ambient thermal resistance, in °C/W,
- P_D max is the sum of P_{INT} max and $P_{I/O}$ max (P_D max = P_{INT} max + $P_{I/O}$max),
- P_{INT} max is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.

$P_{I/O}$ max represents the maximum power dissipation on output pins where:

$P_{I/O}$ max = (V_{OL} × I_{OL}) + ((V_{DD} – V_{OH}) × I_{OH}),

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 73. Thermal characteristics

Symbol	Parameter	Value	Unit
$_{JA}$	**Thermal resistance junction-ambient** UFBGA100 - 7 x 7 mm	59	°C/W
	Thermal resistance junction-ambient LQFP100 - 14 x 14 mm / 0.5 mm pitch	43	
	Thermal resistance junction-ambient LQFP64 - 10 x 10 mm / 0.5 mm pitch	46	
	Thermal resistance junction-ambient WLCSP63 - 0.400 mm pitch	49	
	Thermal resistance junction-ambient LQFP48 - 7 x 7 mm / 0.5 mm pitch	55	
	Thermal resistance junction-ambient UFQFPN48 - 7 x 7 mm / 0.5 mm pitch	33	

9 Revision History

Table 75. Document revision history

Date	Revision	Changes
21-Feb-2012	1	Initial release.
12-Oct-2012	2	Added WLCSP63 package. Updated Figure 1: Ultra-low-power STM32L162xC block diagram. Changed maximum number of touch sensing channels to 34, and updated Table 2: Ultralow power STM32L15xxC device features and peripheral counts. Added Table 4: Functionalities depending on the working mode (from Run/active down to standby), and Table 3: ange depending on dynamic voltage scaling. Updated Section 3.10: ADC (analog-to-digital converter) to add Section 3.10.1: Temperature sensor and Section 3.10.2: Internal voltage reference (VREFINT). Updated Figure 3: STM32L162VC LQFP100 pinout. Table 10: STM32L15xxC pin definitions: updated name of reference manual in footnote 5. Changed I2C1_SMBAI into I2C1_SMBA in Table 10: STM32L15xxC pin definitions. Modified PB10/11/12 for AFIO4 alternate function, and replaced LBAR by NADV for AFIO12 in Table 10: Alternate function input/output. Removed caution note below Figure 8: Power supply scheme. Added Note 2 in Table 15: Embedded reset and power control block characteristics. Updated Table 14: General operating conditions. Updated Table 22: Typical and maximum current consumptions in Stop mode and added Note 6. Updated Table 23: Typical and maximum current consumptions in Standby mode. Updated t_{WUSTOP} in Table : . Updated Table 26: Peripheral current consumption. Updated Table 60: SPI characteristics, added Note 1 and Note 3, and applied Note 2 to $t_{r(SCK)}$, $t_{f(SCK)}$, $t_{w(SCKH)}$, $t_{w(SCKL)}$, $t_{su(MI)}$, $t_{su(SI)}$, $t_{h(MI)}$, and $t_{h(SI)}$. Added Table 61: I2S characteristics, Figure 29: I2S slave timing diagram (Philips protocol)(1) and Figure 30: I2S master timing diagram (Philips protocol)(1). Updated Table 72: Temperature sensor characteristics. Added Figure 40: Thermal resistance.